## **Supporting information**

## Outstanding thermoelectric properties in solvothermalsynthesized $Sn_{1-3x}In_xAg_{2x}Te$ micro-crystals through defect engineering and band tuning

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**Figure S1**. Thermal diffusivity *D* as a function of temperature for different  $Sn_{1-}_{3x}In_xAg_{2x}Te$ .



**Figure S2**. Specific heat  $(C_p)$  of  $Sn_{1-3x}In_xAg_{2x}Te$  samples



Figure S3. EDS spectrum and compositional analyses of spot A and B from Figure 1e.



**Figure S4.** (a) A typical SEM image of the sintered  $Sn_{0.85}In_{0.05}Ag_{0.10}Te$  pellet and (b-e) Corresponding EDS elemental map data of Sn, Te, In and Ag.



**Figure S5.** Extended (200) peak of **Figure 2**a shows peaks are shifting towards higher angle demonstrating the lattice shrinkage of the lattice.



**Figure S6.** Calculated Lorenz number *L* as function of temperature of  $Sn_{1-3x}In_xAg_{2x}Te$ .